

Docket Number: 1875.0230000

As a below named inventor, I hereby declare that:

My residence, mailing address and citizenship are as stated below next to my name.

I believe I am the original, first and sole inventor (if only one name is listed below) or an original, first and joint inventor (if plural names are listed below) of the subject matter that is claimed and for which a patent is sought on the invention entitled High Density Metal Capacitor Using Via Etch Stopping Layer as Field Dielectric in Dual-Damascence Interconnect Process, the specification of which is attached hereto unless the following box is checked:

Frocess, the specification of wi	nen is attached hereto timess the	ronowing box is enecked.		
		nal Application Number).	; and	
I hereby state that I have review amended by any amendment re		f the above identified specification, i	neluding the claims, as	
I acknowledge the duty to discl	ose information that is material to	patentability as defined in 37 C.F.R	. § 1.56.	
inventor's certificate, or § 365(a United States listed below, and	<ul> <li>a) of any PCT international application</li> <li>b) dentified below any form</li> </ul>	i-(d) or § 365(b) of any foreign application, which designated at least one coreign application for patent or inventoplication on which priority is claime	country other than the or's certificate, or PCT	
Prior Foreign Application(s)			Priority Claimed	
(Application No.)	(Country)	(Day Month Year Filed)	□ Yes □ No	
(Application No.)	(Country)	(Day Month Year Filed)	□ Yes □ No	
		d States provisional application(s) lis	sted below.	
(Application No.)	(Filing Date)			
(Application No.)	(Filing Date)			
international application design this application is not disclosed paragraph of 35 U.S.C. § 112. I	ating the United States, listed bel in the prior United States or PCT acknowledge the duty to disclose	States application(s), or under § 365(c) ow and, insofar as the subject matter international application in the mande information that is material to pater e prior application and the national o	of each of the claims of ner provided by the first ntability as defined in 37	
(Application No.)	(Liling Date)	(Status - patented, pe	(Status - patented, pending, abandoned)	
(Application No.)	(Filing Date)	(Status - patented, pe	(Status - patented, pending, abandoned)	

Appl. No.: To Be Assigned Docket No.: 1875.0230000

Send Correspondence to:

STERNE, KESSTER, GOLDSTEIN & FOX P.L.L.C. 1100 New York Avenue, N.W. Suite 600 Washington, D.C. 20005-3934

Direct Telephone Calls to:

(202) 371-2600

I hereby declare that all statements made herein of my own knowledge are true and that all statements made on information and belief are believed to be true; and further that these statements were made with the knowledge that willful false statements and the like so made are punishable by fine or imprisonment, or both, under Section 1001 of Title 18 of the United States Code and that such willful false statements may jeopardize the validity of the application or any patent issued thereon.

Full name of sole or first inventor	Liming Tsau	
Signature of sole or first inventor	Timing France 12302	Date ∵ €
Residence	Irvine. California	
Citizenship	Taiwan, ROC	
Mailing Address	14591 Fir Avenue	
	Irvine, California 92606	
Full name of second inventor		
Signature of second inventor		Date
Residence		
Citizenship		
Mailing Address		
Full name of third inventor		
Signature of third inventor		Date
Residence		
Citizenship		
Mailing Address		

(Supply similar information and signature for subsequent joint inventors, if any)